

HA13536F

Three-Phase Brushless DC Motor Driver IC

HITACHI

ADE-207-111B (Z)
3rd Edition
July 1996

Description

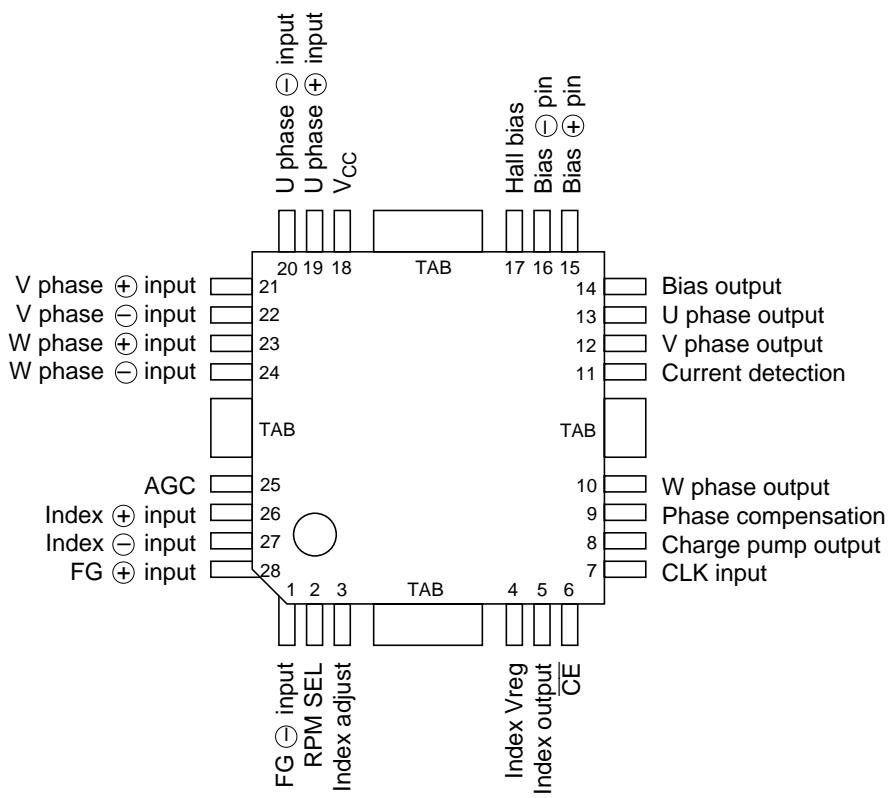
The HA13536F is a 3-phase brushless DC motor driver IC with digital speed control. It is being developed for direct drive of the spindle motor of 5 V floppy disk drives with a height of 3/4" or less. It has the following functions and features.

Functions

- 1.0 A per phase, 3-phase drive circuit (current driver)
- Digital speed control circuit
- FG Amp
- Index circuit
- Current limiter circuit
- Over-temperature shutdown circuit (OTSD)

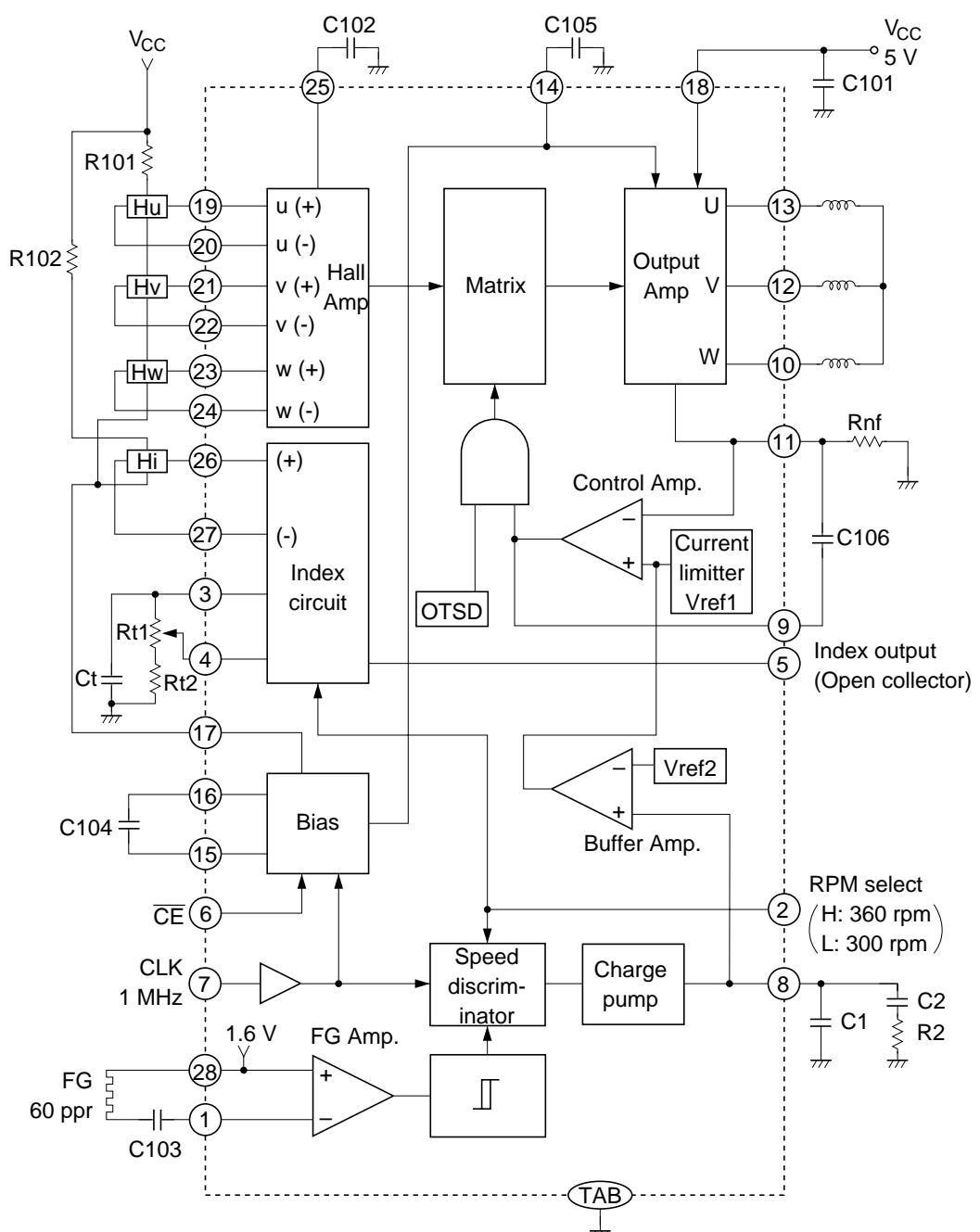
Features

- Low saturation voltage, typically 1.15 V (at 0.7 A)
- Soft switching drive circuit
- No need for an output snubber circuit

Pin Arrangement

(Top view)

Block Diagram



Note : Pin arrangement is preliminary specification.

Pin Function

Pin Number	Pin Name	Function	Pin Voltage
1	FG (-) input	FG Amp. (-) input terminal	
2	RPMSEL	Change terminal for motor rotation speed “L” → 300 rpm, “H” → 360 rpm	V _{TH} = 1.4 V Typ
3	Index adjustment	Terminal to set up burst time of index circuit	0 V Min, 1.2 V Max
4	Index Vreg	Output terminal for fixed voltage of index circuit	1.5 V Typ
5	Index output	Index output terminal (Open collector)	V _{OL} = 0.14 V Typ (@I _O = 2 mA)
6	\overline{CE}	Chip enable terminal “L”: enable, “H”: disable	V _{TH} = 1.4 V Typ
7	CLK input	CLK input terminal	V _{TH} = 1.4 V Typ
8	C-PUMP output	Speed error Integration and Phase compensation of speed control	
9	Phase compensation	To prevent the parasitic oscillation of output, insert the capacitor between pin 9 and pin 11.	
10	W phase output	W phase output	
11	Current detection	Output current detection and terminal which is connected with phase compensation capacitor for current control.	
12	V phase output	V phase output	
13	U phase output	U phase output	
14	Bias output	Bias output terminal	
15	Bias (+) pin	Bias (+) pin terminal	
16	Bias (-) pin	Bias (-) pin terminal	
17	Hall bias	Hall bias terminal \overline{CE} = “L” → Bias, \overline{CE} = “H” → High impedance	2.2 V Typ (@I = 10 mA)
18	V _{cc}	Power supply	4.25 V Min, 6.5 V Max
19	U phase (+) input	U phase (+) input terminal	2.0 V Min, V _{cc} – 0.5 V Max
20	U phase (-) input	U phase (-) input terminal	2.0 V Min, V _{cc} – 0.5 V Max
21	V phase (+) input	V phase (+) input terminal	2.0 V Min, V _{cc} – 0.5 V Max
22	V phase (-) input	V phase (-) input terminal	2.0 V Min, V _{cc} – 0.5 V Max
23	W phase (+) input	W phase (+) input terminal	2.0 V Min, V _{cc} – 0.5 V Max
24	W phase (-) input	W phase (-) input terminal	2.0 V Min, V _{cc} – 0.5 V Max
25	AGC	Hall amp output wave form adjustment terminal (Insert capacitor C102 between GND)	

Pin Function (cont)

Pin Number	Pin Name	Function	Pin Voltage
26	Index (+) input	Index amp (+) input terminal	1.4 V Min, $V_{cc} - 0.5$ V Max
27	Index (-) input	Index amp (-) input terminal	1.4 V Min, $V_{cc} - 0.5$ V Max
28	FG (+) input	FG amp (+) input terminal	DC bias 1.6 V Typ

External Parts

Part Number	Recommended Value	Purpose	Notes
R2	—	Integration constant	1
R101	—	Hall bias	
R102	—	Index hall bias	
Rnf	—	Current detection and limitation	2
Rt1	0 to 50 kΩ	Index burst adjustment	3
Rt2	100 kΩ	Index pulse width setting	
C1, C2	—	Integration constants	1
C101	$\geq 0.1 \mu F$	Power supply bypass	4
C102	0.1 μF	AGC filter	5
C103	0.47 μF	FG amp. coupling	5
C104	0.1 μF	Bias	
C105	$\geq 0.1 \mu F$	Bias	7
C106	0.1 μF	Phase compensation	4
Ct	0.1 μF	Index setting	3, 6

Notes: 1. Determine the integration constants from the following formulas:

$$\omega_0 \leq \frac{2\pi f_{FG}}{20} \quad (\text{rad/s})$$

$$R2 = \frac{1}{9.55} \frac{J\omega_0 N_O \cdot Rnf}{K_T Gctl Icp} \quad (\Omega)$$

$$C1 = \frac{1}{\sqrt{10}} \frac{1}{\omega_0 R2} \quad (F)$$

$$C2 = 10C1 \quad (F)$$

In the above formulas:

ω_o = Time constant of servo loop

f_{FG} = FG frequency in Hz

N_o = Motor speed in rpm

J = Motor moment of inertia in $\text{kg}\cdot\text{cm}\cdot\text{s}^2$

K_T = Motor torque constant in $\text{kg}\cdot\text{cm}/\text{A}$

Rnf = Current detection in Ω

$Gctl$ = Control amp gain (see Electrical Characteristics)

Icp = Charge pump output current (see Electrical Characteristics)

2. The current limiter operates according to the following formula:

$$I_{OMAX} = \frac{Vref1}{Rnf} \quad (\text{A})$$

where $Vref1$ is the current limiter reference voltage (see Electrical Characteristics)

3. The burst time $t1$ is defined as follows:

$$t1 \approx -Ct \times Rt1' \times \ln(1 - Vth1(L) / Vreg) \quad (\text{RPM select input low})$$

$$t1 \approx -Ct \times Rt1' \times \ln(1 - Vth1(H) / Vreg) \quad (\text{RPM select input high})$$

where $Rt1'$ is resistance value inter 3 to 4 pin.

4. Place as close to the IC as possible.

5. Determine $C102$ and $C103$ according to the following formulas:

$$C102 \geq \frac{200}{N_o P} \quad (\mu\text{F})$$

$$C103 \geq \frac{100}{f_{FG}} \quad (\mu\text{F})$$

where

P = Number of motor poles

6. The index pulse width $t2$ is determined as follows:

$$t2 \approx -Ct \times Rt2' \times \ln(Vth1 / Vth2)$$

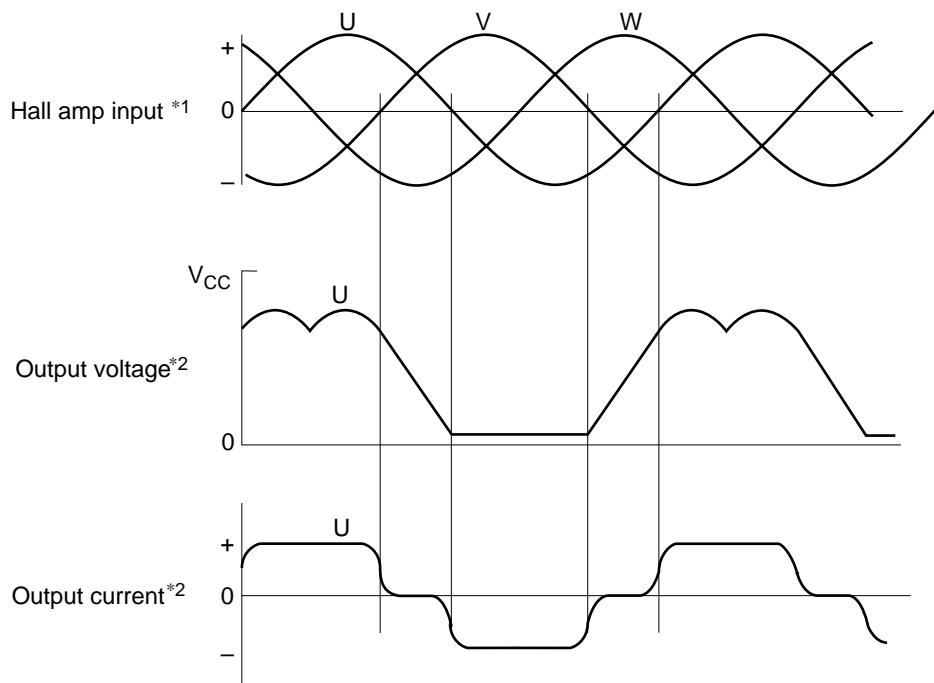
where $Vth2$ is the threshold voltage (see Electrical Characteristics).

$Rt2'$: $Rt1$ (max) + $Rt2$

7. If the circuit is affected by noise, a large capacitance value should be set.

Timing Waveforms

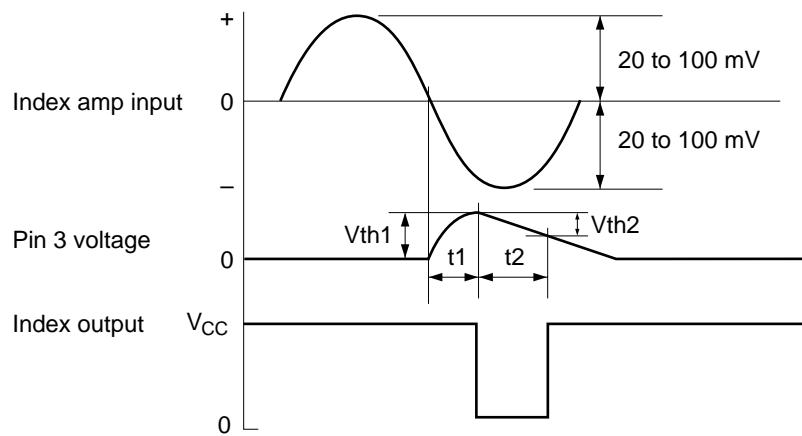
Hall Amp Input vs. Output Voltage and Current



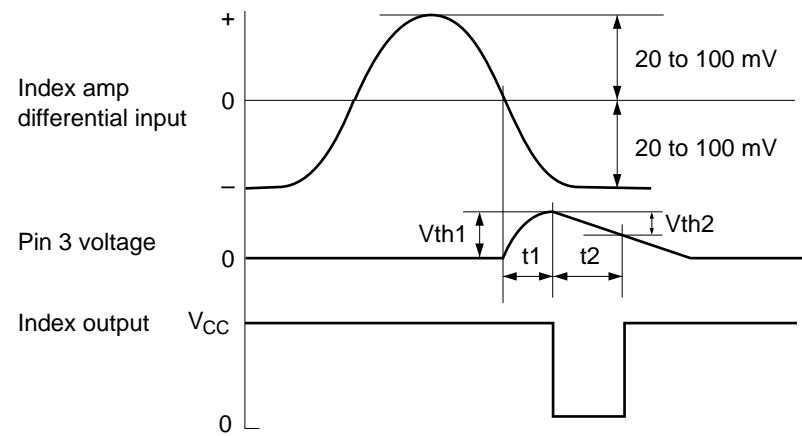
- Notes:
1. The input waveforms to the hall amp should be sine waves with a third harmonic content of less than 20%.
 2. Only the U phase output is shown.

Index Amp Input vs. Output

- Application 1



- Application 2



Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Value	Unit	Notes
Power supply voltage	V _{CC}	7	V	1
Input voltage	V _{IN}	0 to V _{CC} + 0.3	V	2
Peak output current	I _{OP}	1.0	A	
Normal output current	I _O	0.7	A	
Power dissipation	P _T	1.5	W	3
Junction temperature	T _J	+150	°C	1
Storage temperature range	T _{STG}	-55 to +125	°C	

Notes:

- The operating ranges is:

$$V_{CC} = 4.25 \text{ to } 6.5 \text{ V}$$

$$T_{JOPR} = 0 \text{ to } +125^\circ\text{C}$$

- Applied to the \overline{CE} , CLK, and RPM SEL pins.

- Permissible value when T_{pin} = 113°C and thermal resistance is as follows:

$$\theta_{j-pin} \leq 25^\circ\text{C/W}$$

$$\theta_{j-a1} \leq 55^\circ\text{C/W} \text{ (when mounted on a metal substrate)}$$

$$\theta_{j-a2} \leq 80^\circ\text{C/W} \text{ (when mounted on a glass epoxy substrate)}$$

Electrical Characteristics (Ta = 25°C, V_{CC} = 5 V)

Item	Symbol	Min	Typ	Max	Unit	Test conditions	Pin Nos.	Notes
Quiscent current	I _{CC0}	—	—	0.45	mA	$\overline{CE} = H, V_{CC} = 6.5 V$	18	
	I _{CC}	—	9	13	mA	$\overline{CE} = L, V_{CC} = 6.5 V$		
Logic input	Input current I _{I1} (6 pin)	-80	—	2	μA	$V_{CE} = 0$ to 6.5 V	2, 6, 7	
	Input current I _{I2} (2 pin)	-2	—	100	μA	$V_{RPM} = 5.5 V$		
	Input current I _{I3} (7 pin)	-2	—	450	μA	$V_{CLK} = 5.5 V$		
	Input low voltage	V _{IL}	0	—	0.8	V		
	Input high voltage	V _{IH}	2.0	—	5.5	V		
Logic output	Output low voltage	V _{OL}	—	—	0.4	V	I _O = 2 mA	5
	Leakage current	I _{OH}	—	—	±10	μA	$V_{CE} = 7.0 V$	
Hall amp	Input resistance	R _H	7	10	13	kΩ		19 to 24
	Common-mode input voltage range	V _H	2.0	—	$V_{CC} - 0.5$	V		
	Differential input voltage range	V _h	30	—	160	mV _{PP}		
Output amp	Leakage current	I _{CER(H)}	0	—	5	mA	$V_O = 7.0 V$	10, 12, 13
		I _{CER(L)}	—	—	±100	μA	$V_O = 0 V$	
	Saturation voltage	V _{SAT1}	—	1.15	1.65	V	I _O = 0.7 A	
		V _{SAT2}	—	0.6	0.85	V	I _O = 0.35 A	1
FG amp and detector	Input voltage range	V _{FG}	2	—	20	mV _{PP}		1, 28
	Noise margin	nd	—	—	0.5	mV _{PP}	Differential Noise	
		nc	—	—	0.5	V	COMMON Noise	

Electrical Characteristics ($T_a = 25^\circ\text{C}$, $V_{CC} = 5 \text{ V}$) (cont)

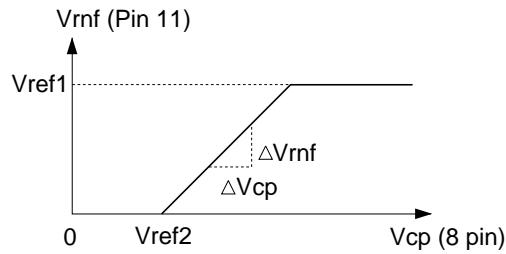
Item	Symbol	Min	Typ	Max	Unit	Test conditions	Pin Nos.	Notes
Speed discriminator and charge pump	Number of counts	N	—	1666.5	—	—	PRMSEL = L	
		—	1388.5	—	—	PRMSEL = H		
Operating frequency	f_{CLK}	0.9	1.0	1.1	MHz		7	
Leakage current	I_{off}	—	—	± 50	nA	$V_8 = 0.8 \text{ V}$	8	
Output current	I_{cp+}	7	10	13	μA	Speed reduction full scale		
	I_{cp-}	-7	-10	-13	μA	Acceleration full scale		
Current control	Threshold voltage	V_{ref2}	0.55	0.63	0.71	V	8	2
	Voltage gain	G_{ctl}	-12	-10	-8	dB	11	
	Current limitter voltage	V_{ref1}	157	175	193	mV	$R_{NF} = 0.47 \Omega$	
Index circuit	Input voltage (common)	V_{index}	1.4	—	$V_{CC} - 0.5$	V	26, 27	3
	Input voltage (different)	V_{index}	40	—	300	mVpp		
	Hysteresis	hys	—	14	—	mV		
	Input current	—	—	± 2	μA		3	
	Threshold voltage	V_{th1}	$0.60 \times V_{reg}$	$0.64 \times V_{reg}$	$0.68 \times V_{reg}$	V	RPM select = L	
			$0.54 \times V_{reg}$	$0.58 \times V_{reg}$	$0.62 \times V_{reg}$	V	RPM select = H	
	Ct discharge threshold voltage	V_{th2}	$0.50 \times V_{reg}$	$0.54 \times V_{reg}$	$0.58 \times V_{reg}$	V	RPMSEL = L	3
			$0.44 \times V_{reg}$	$0.48 \times V_{reg}$	$0.52 \times V_{reg}$	V	RPMSEL = H	3
	Bias	V_{reg}	1.3	1.5	1.7	V	$I_o = -0.2 \text{ mA}$	4
Hall bias	Output voltage	V_{hb}	1.9	2.2	2.5	V	$I_h = 10 \text{ mA}, \overline{CE} = L$	17

Electrical Characteristics (Ta = 25°C, V_{CC} = 5 V) (cont)

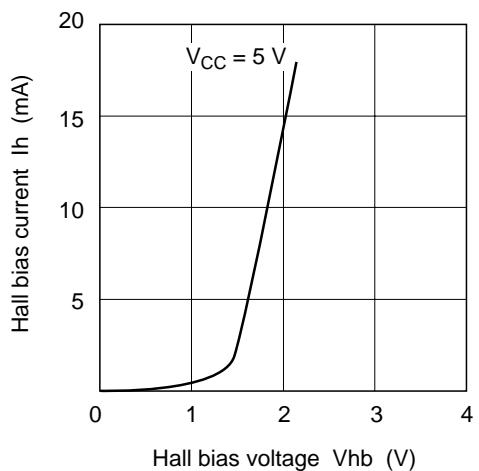
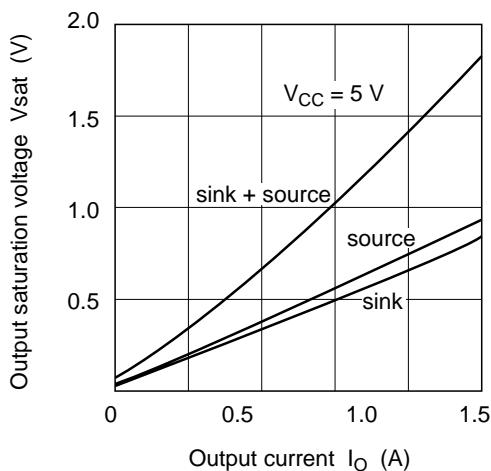
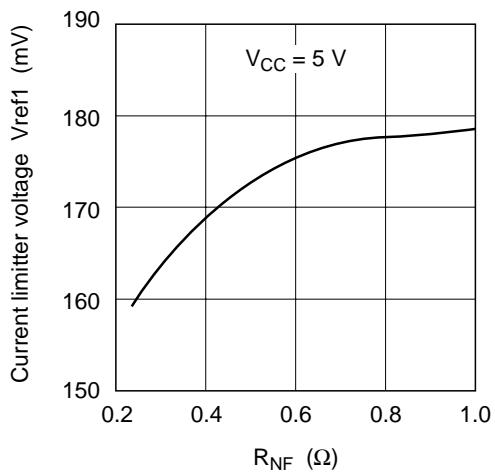
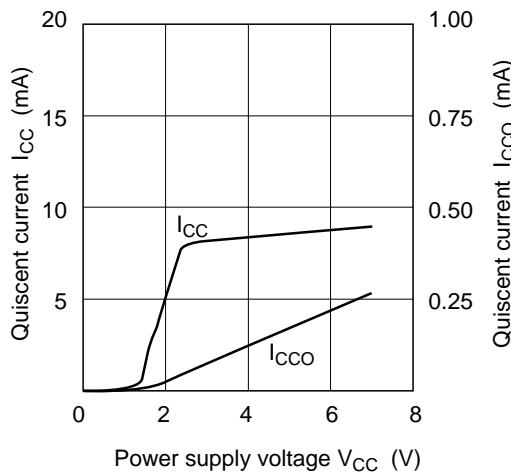
Item		Symbol	Min	Typ	Max	Unit	Test conditions	Pin Nos.	Notes
Hall bias	Leakage current	I _{hof}	—	—	±10	μA	C _E = H, V _{hb} = 7.0 V	17	
OTSD	Operating temperature	T _{sd}	125	150	—	°C			4

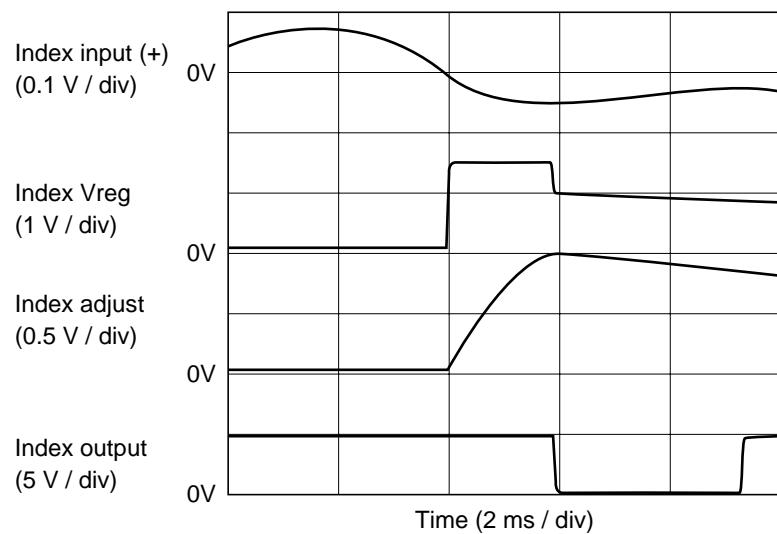
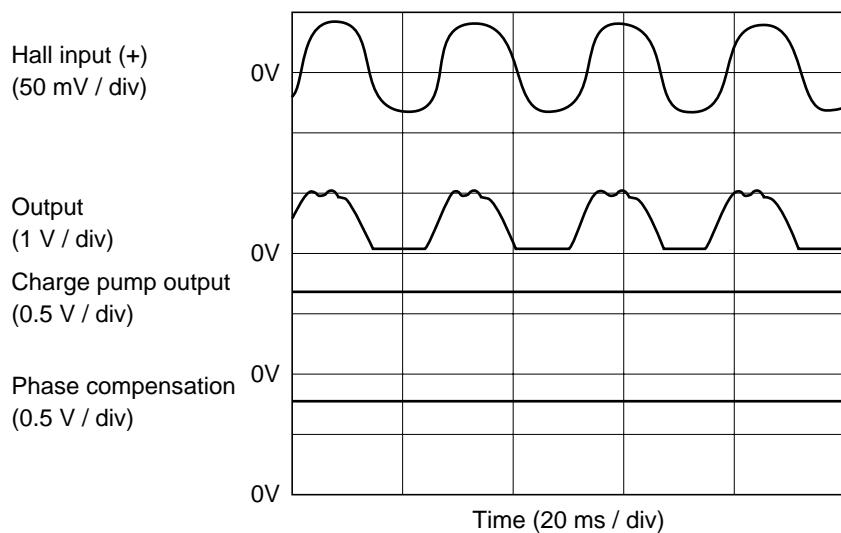
Notes: 1. Total of sink and source.

2. See figure 1. $G_{tl} = \Delta V_{rnf}/\Delta V_{cp}$.
3. Refer to the timing chart.
4. Design parameter only (No test).

**Figure 1**

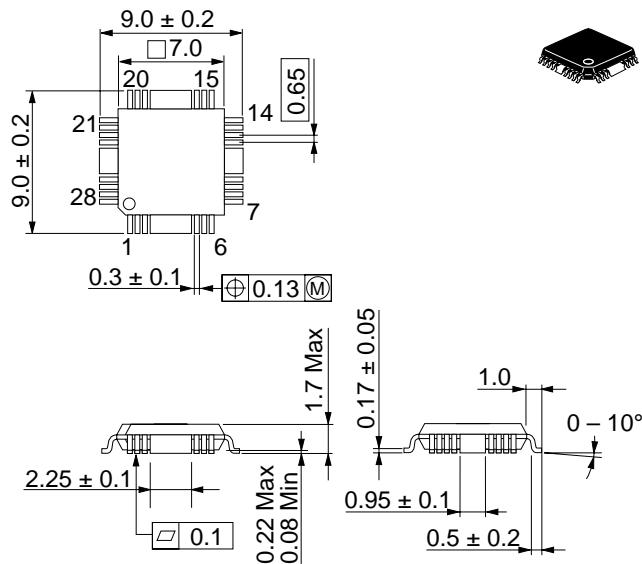
Reference Data



Mount Waveform Characteristics

Package Dimensions

Unit: mm



Hitachi code	FP-28T
EIAJ code	—
JEDEC code	—

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